

**PATENT**  
Atty. Docket No. ASC-025DV2C1  
(058420/157357)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

APPLICANTS: Cheng et al.

SERIAL NUMBER: 10/802,186

ART UNIT: 2854

FILING DATE: March 17, 2004

EXAMINER: Hu, Shouxiang

TITLE: PROCESS FOR PRODUCING SEMICONDUCTOR ARTICLE  
USING GRADED EPITAXIAL GROWTH

Mail Stop Amendment  
Commissioner for Patents  
P.O. box 1450  
Alexandria, VA 22313-1450

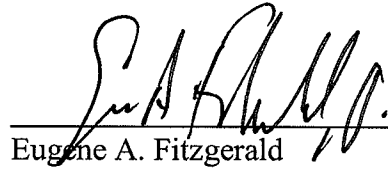
**DECLARATION OF ATTRIBUTION UNDER 37 C.F.R. § 1.132**

I, Eugene A. Fitzgerald, hereby state that:

1. I am a co-inventor in the instant application, U.S.S.N. 10/802,186.
2. I am the only inventor of the subject matter claimed in U.S. Patent No. 6,602,613.
3. I have read and understood the Office Action mailed on March 8, 2007, in the instant application.
4. I, and no other, conceived or invented the subject matter of claims 62, 67–71, 73, and 77 of the instant application.
5. I hereby declare that all statements made herein of my own knowledge are true, and that all statements made on information and belief are believed to be true; and further, that these statements are made with the knowledge that willful false statements, and the like

so made, are punishable by fine or imprisonment, or both, under Section 1001, Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Date: July 30, 2007

  
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Eugene A. Fitzgerald